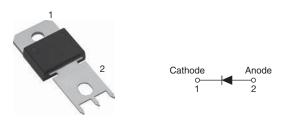
### **VS-85EPF12 Soft Recovery Series**

Vishay Semiconductors

### Fast Soft Recovery Rectifier Diode, 85 A

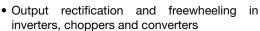


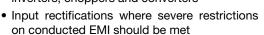
PowerTab®

PRODUCT SUMMARY					
Package	PowerTab <sup>®</sup>				
I <sub>F(AV)</sub>	85 A				
$V_R$	1200 V				
V <sub>F</sub> at I <sub>F</sub>	1.36 V				
I <sub>FSM</sub>	1250 A				
t <sub>rr</sub>	95 ns				
T <sub>J</sub> max.	150 °C				
Diode variation	Single die				
Snap factor	0.5				

#### **FEATURES**

- · Glass passivated pallet chip junction
- 150 °C max. operating junction temperature







RoHS

- · Screw mounting only
- Designed and qualified according to JEDEC®-JESD 47
- AEC-Q101 qualified
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

The VS-85EPF12 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions. Available in the new PowerTab package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdeness connectivity for use in high current environments.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	Rect. conduction 50 % duty cycle at T <sub>C</sub> = 85 °C	85	Λ	
I <sub>F(RMS)</sub>		160	Α Α	
V <sub>RRM</sub>		1200	V	
I <sub>FSM</sub>		1250	Α	
V <sub>F</sub>	100 A, T <sub>J</sub> = 25 °C	1.4	V	
t <sub>rr</sub>	1 A, - 100 A/μs	95	ns	
T <sub>J</sub>	Range	-40 to +150	°C	

VOLTAGE RATINGS					
TYPE NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA		
VS-85EPF12	1200	1300	15		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 85 °C, 180° conduction half sine wave	85		
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	1100	Α	
		10 ms sine pulse, no voltage reapplied	1250		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	5000 A <sup>2</sup> s		
		10 ms sine pulse, no voltage reapplied	7000	A-s	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A <sup>2</sup> √s	

## **VS-85EPF12 Soft Recovery Series**

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	85 A, T <sub>J</sub> = 25 °C		1.36	V
Forward slope resistance	r <sub>t</sub>	- T <sub>J</sub> = 150 °C		4.03	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.87	V
Maximum reverse leakage current	I	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	mA
iviaximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C	VR = nateu VRRM	15	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t <sub>rr</sub>	In at 85 Anu	480	ns	I <sub>FM</sub> t
Reverse recovery current	I <sub>rr</sub>	I <sub>F</sub> at 85 A <sub>pk</sub> 25 Α/μs	7.1	А	
Reverse recovery charge	Q <sub>rr</sub>	25 °C	2.1	μC	dir/ Q
Snap factor	S		0.5		I <sub>RM(REC)</sub>

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistar junction to case	nce,	R <sub>thJC</sub>	DC operation	0.35	
Maximum thermal resistar junction to ambient	nce,	R <sub>thJA</sub>		40	°C/W
Typical thermal resistance case to heatsink	),	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight				0.21	oz.
Manustinastaurus	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf · in)
Marking device			Case style PowerTab®	85EF	PF12

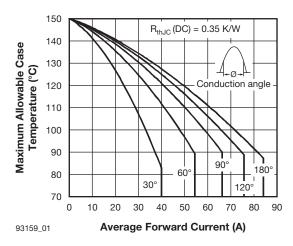


Fig. 1 - Current Rating Characteristics

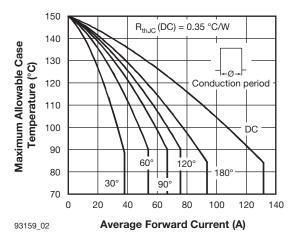


Fig. 2 - Current Rating Characteristics

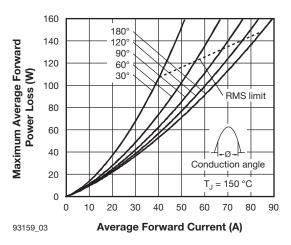


Fig. 3 - Forward Power Loss Characteristics

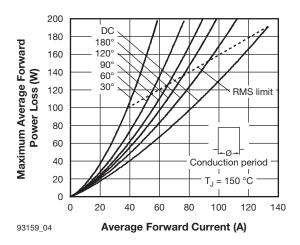


Fig. 4 - Forward Power Loss Characteristics

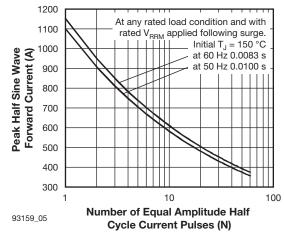


Fig. 5 - Maximum Non-Repetitive Surge Current

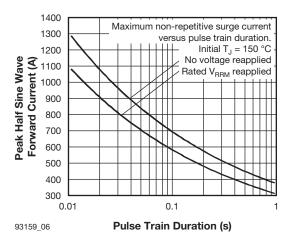


Fig. 6 - Maximum Non-Repetitive Surge Current

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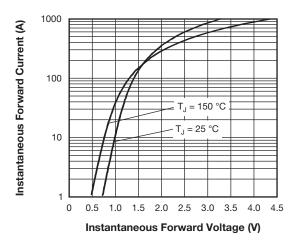
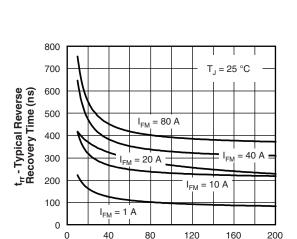


Fig. 7 - Forward Voltage Drop Characteristics



dl/dt - Rate of Fall of Forward Current (A/ $\mu$ s) Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

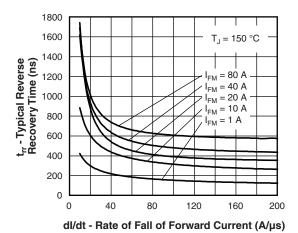


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C

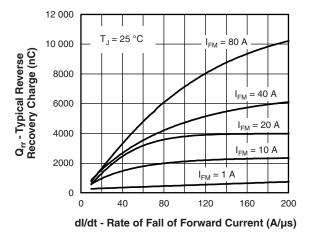


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25$  °C

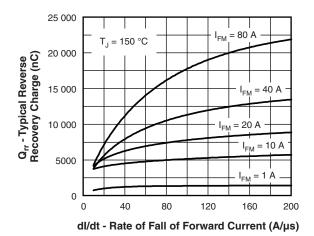
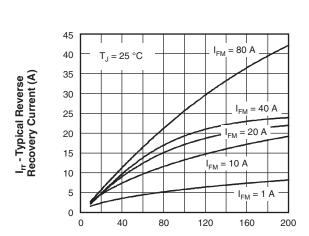


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

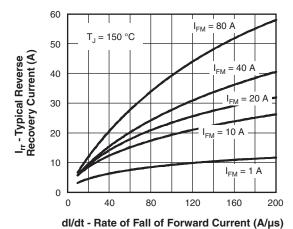


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C



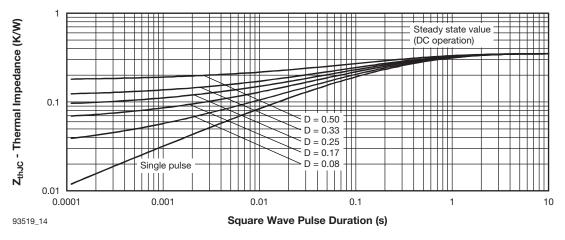


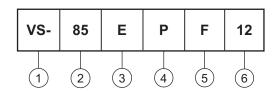
Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics

## **VS-85EPF12 Soft Recovery Series**

Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating

3 - Circuit configuration:

E = Single diode

4 - Package:

P = TO-247AC

5 - Type of silicon:

F = Fast recovery

6 - Voltage code x 100 = V<sub>RRM</sub> (12 = 1200 V)

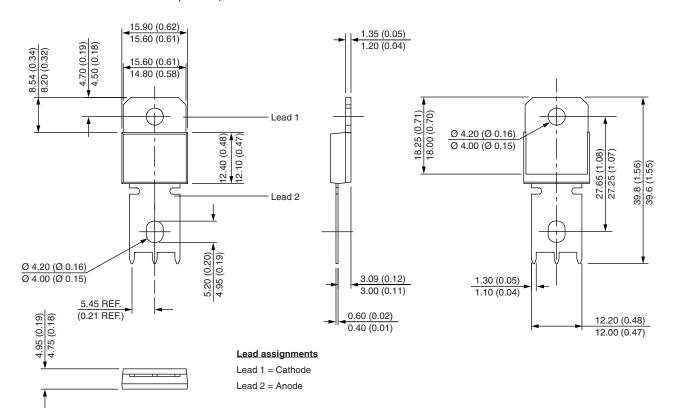
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95240</u>				
Part marking information	www.vishay.com/doc?95370			
Application note	www.vishay.com/doc?95179			



### Vishay Semiconductors

#### PowerTab<sup>®</sup>

#### **DIMENSIONS** in millimeters (inches)





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Vishay

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